## NSN 5961-00-989-7530

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View Online at https://aerobasegroup.com/nsn/5961-00-989-7530 **Inclosure Material:** Metal **Overall Length:** 0.546 inches **Terminal Length:** 0.562 inches **Overall Diameter:** 1.281 inches **Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method: Terminal Terminal Circle Diameter:** 0.750 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 50.0 breakdown voltage, collector-to-base, emitter open and 50.0 breakdown voltage, collector-to-emitter, base open and 15.0 breakdown voltage, emitter-to-base, collector open **Current Rating Per Characteristic:** Between 1.00 amperes source cutoff current and 10.00 amperes source cutoff current **Power Rating Per Characteristic:** 150.0 watts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 100.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 1 threaded stud and 2 tab, solder lug **Specification Data:** 80131-release3577 professional/industrial association specification Shelf Life: N/a **Unit Of Measure: Demilitarization:** 

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